

# DATA SHEET

**J174; J175;  
J176; J177**  
P-channel silicon field-effect  
transistors

Product specification  
File under Discrete Semiconductors, SC07

April 1995

**P-channel silicon field-effect transistors**

**J174; J175;  
J176; J177**

**DESCRIPTION**

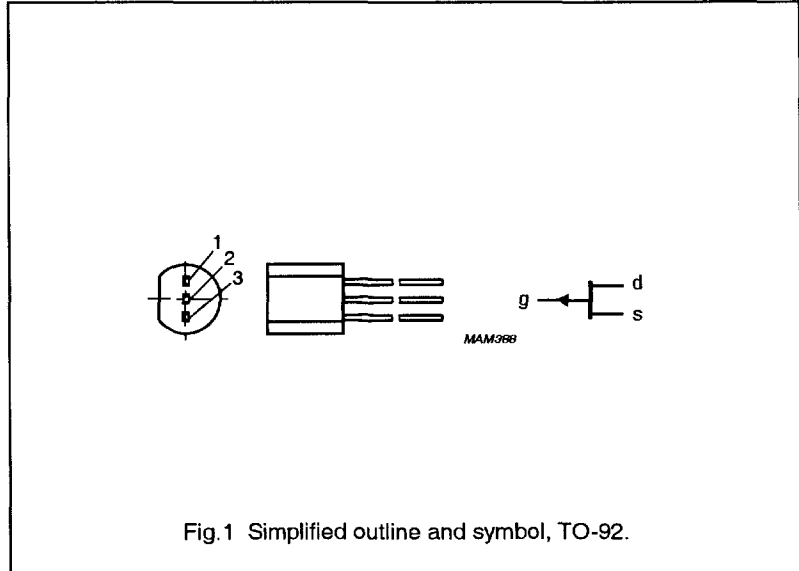
Silicon symmetrical p-channel junction FETs in a plastic TO-92 envelope and intended for application with analog switches, choppers, commutators etc.

A special feature is the interchangeability of the drain and source connections.

**PINNING**

- 1 = source
- 2 = gate
- 3 = drain

Note: Drain and source are interchangeable.



**QUICK REFERENCE DATA**

Drain-source voltage	$\pm V_{DS}$	max.	30	V			
Gate-source voltage	$V_{GSO}$	max.	30	V			
Gate current	$-I_G$	max.	50	mA			
Total power dissipation up to $T_{amb} = 50\text{ }^\circ\text{C}$	$P_{tot}$	max.	400	mW			
			<b>J174</b>	<b>J175</b>	<b>J176</b>	<b>J177</b>	
Drain current							
$-V_{DS} = 15\text{ V}; V_{GS} = 0$	$-I_{DSS}$	min.	20	7	2	1.5	mA
		max.	135	70	35	20	mA
Drain-source ON-resistance							
$-V_{DS} = 0.1\text{ V}; V_{GS} = 0$	$R_{DS\ on}$	max.	85	125	250	300	$\Omega$

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**RATINGS**

Limiting values in accordance with the Absolute Maximum System (IEC 134)

Drain-source voltage	$\pm V_{DS}$	max.	30	V
Gate-source voltage	$V_{GSO}$	max.	30	V
Gate-drain voltage	$V_{GDO}$	max.	30	V
Gate current (DC)	$-I_G$	max.	50	mA
Total power dissipation up to $T_{amb} = 50\text{ }^\circ\text{C}$	$P_{tot}$	max.	400	mW
Storage temperature range	$T_{stg}$		-65 to +150	$^\circ\text{C}$
Junction temperature	$T_j$	max.	150	$^\circ\text{C}$

**THERMAL RESISTANCE**

From junction to ambient in free air	$R_{th\ j-a}$	=	250	K/W
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**STATIC CHARACTERISTICS**

$T_j = 25\text{ }^\circ\text{C}$  unless otherwise specified

			J174	J175	J176	J177
Gate cut-off current $V_{GS} = 20\text{ V}; V_{DS} = 0$	$I_{GSS}$	max.	1	1	1	1 nA
Drain cut-off current $-V_{DS} = 15\text{ V}; V_{GS} = 10\text{ V}$	$-I_{DSX}$	max.	1	1	1	1 nA
Drain current $-V_{DS} = 15\text{ V}; V_{GS} = 10\text{ V}$	$-I_{DSS}$	min.	20	7	2	1.5 mA
		max.	135	70	35	20 mA
Gate-source breakdown voltage $I_G = 1\text{ }\mu\text{A}; V_{DS} = 0$	$V_{(BR)GSS}$	min.	30	30	30	30 V
Gate-source cut-off voltage $-I_D = 10\text{ nA}; V_{DS} = -15\text{ V}$	$V_{GS\ off}$	min.	5	3	1	0.8 V
		max.	10	6	4	2.25 V
Drain-source ON-resistance $-V_{DS} = 0.1\text{ V}; V_{GS} = 0$	$R_{DSon}$	max.	85	125	250	300 $\Omega$

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**DYNAMIC CHARACTERISTICS**

$T_j = 25\text{ }^\circ\text{C}$  unless otherwise specified

Input capacitance,  $f = 1\text{ MHz}$

$V_{GS} = 10\text{ V}; V_{DS} = 0\text{ V}$

$V_{GS} = V_{DS} = 0$

Feedback capacitance,  $f = 1\text{ MHz}$

$V_{GS} = 10\text{ V}; V_{DS} = 0\text{ V}$

Switching times (see Fig.2 + 3)

Delay time

Rise time

Turn-on time

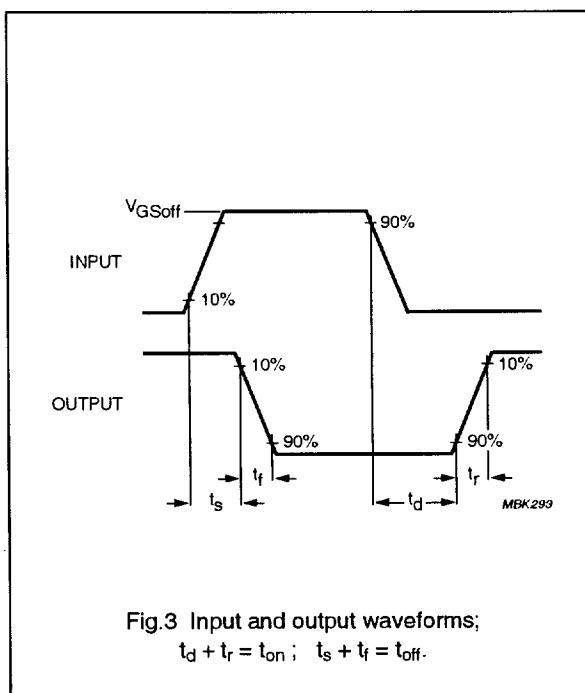
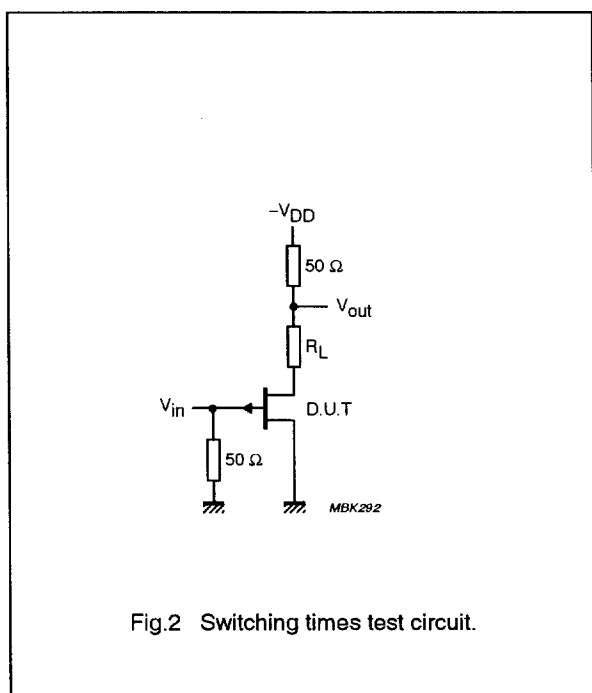
Storage time

Fall time

Turn-off time

Test conditions:

$C_{is}$	typ.	8			pF		
$C_{is}$	typ.	30			pF		
$C_{rs}$	typ.	4			pF		
			<b>J174</b>	<b>J175</b>	<b>J176</b>	<b>J177</b>	
$t_d$	typ.	2	5	15	20	ns	
$t_r$	typ.	5	10	20	25	ns	
$t_{on}$	typ.	7	15	35	45	ns	
$t_s$	typ.	5	10	15	20	ns	
$t_f$	typ.	10	20	20	25	ns	
$t_{off}$	typ.	15	30	35	45	ns	
$-V_{DD}$		10	6	6	6	V	
$V_{GS\ off}$		12	8	6	3	V	
$R_L$		560	1200	2000	2900	$\Omega$	
$V_{GS\ on}$		0	0	0	0	V	



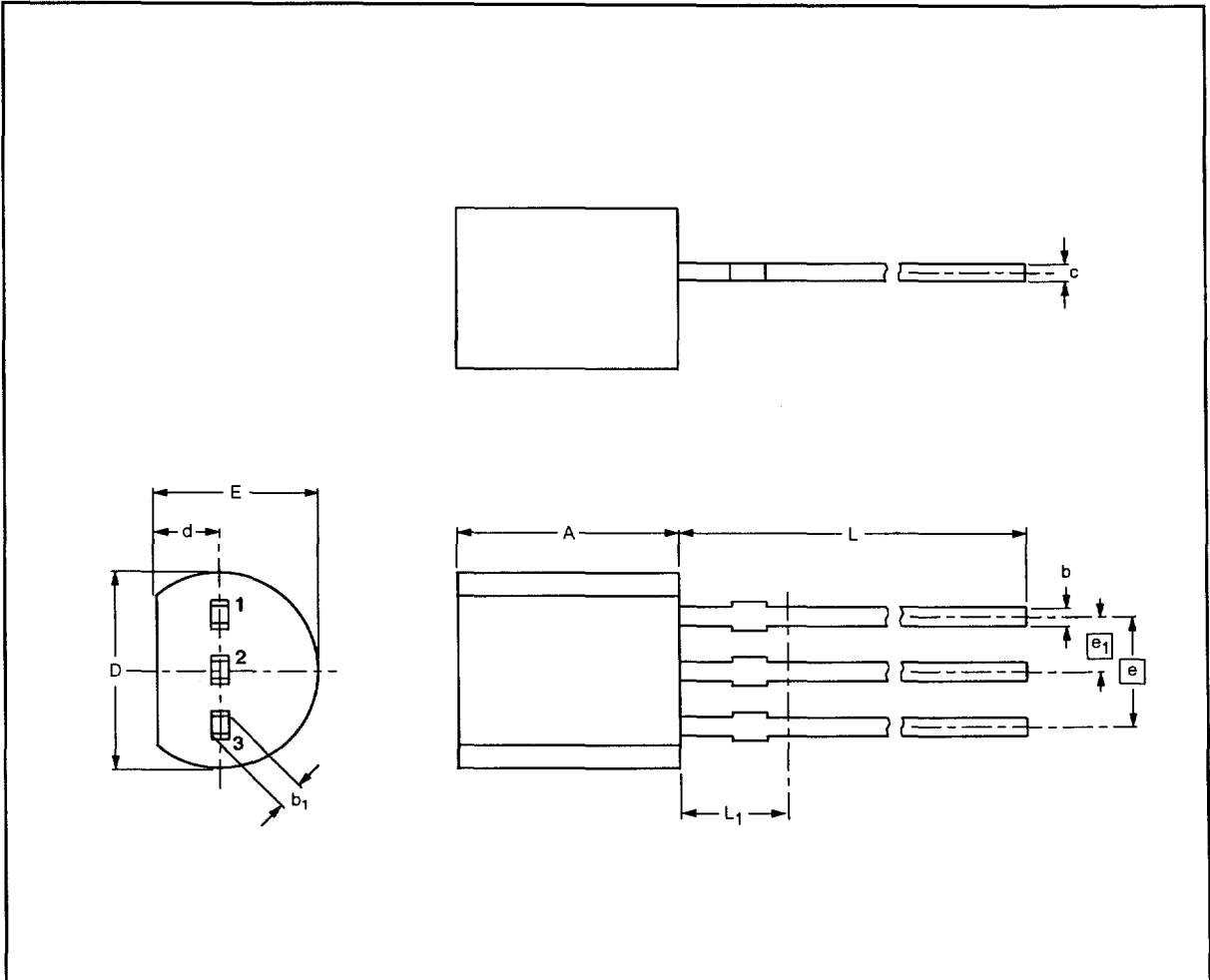
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PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



DIMENSIONS (mm are the original dimensions)

UNIT	A	b	b <sub>1</sub>	c	D	d	E	e	e <sub>1</sub>	L	L <sub>1</sub> (1)
mm	5.2 5.0	0.48 0.40	0.66 0.56	0.45 0.40	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ		
SOT54		TO-92	SC-43		97-02-28

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**DEFINITIONS**

<b>Data sheet status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Short-form specification	The data in this specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.
<b>Limiting values</b>	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
Where application information is given, it is advisory and does not form part of the specification.	

**LIFE SUPPORT APPLICATIONS**

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Product Information

# J174; J175; J176; J177; P-channel silicon field-effect transistors

Information as of 2001-11-13

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## Description

Silicon symmetrical p-channel junction FETs in a plastic TO-92 envelope and intended for application with analog switches, choppers, commutators etc.

A special feature is the interchangeability of the drain and source connections.

## Datasheet

Type number	Title	Publication release date	Datasheet status	Page count	File size (kB)	Datasheet
J174; J175; J176; J177	P-channel silicon field-effect transistors	01-Apr-95	Product Specification	6	30	<a href="#">Download</a> <a href="#">Download</a>

## Parametrics

Type number	Package	$V_{DS}(V)$	$-V(P)GS_{MAX}(V)$	$-V(P)GS(V)$	CRS MAX(pF)	$t_{on}$ MAX(ns)	$t_{off}$ MAX(ns)	$I_{DSS}$ MIN.(mA)	$I_{DSS}$ MAX.(mA)	$R_{DS(on)}$ MAX(Ohm)	$-V(P)GS$ MIN(V)	CRS TYP(pF)	$t_{on}$ TYP(ns)	$t_{off}$ TYP(ns)	$I_G(mA)$	$I_{DSS}$ MIN MAX(mA)	IG
J174	<a href="#">SOT54</a> (TO-92, SC-43, SPT, E-1)	30	10	5 to 10	4	7	15	20	135	85	5	4	7	15	50	20 to 135	50

J175	<a href="#">SOT54</a> (TO-92, SC-43, 30 SPT, E-1)	6	3 to 6	4	15	30	7	70	125	3	4	15	30	50	7 to 70	50
J176	<a href="#">SOT54</a> (TO-92, SC-43, 30 SPT, E-1)	4	1 to 4	4	35	35	2	35	250	1	4	35	35	50	2 to 35	50
J177	<a href="#">SOT54</a> (TO-92, SC-43, 30 SPT, E-1)	2.25	0.8 to 2.25	4	45	45	1.5	20	300	0.8	4	45	45	50	1.5 to 20	50

## Products, packages, availability and ordering

<u>Type number</u>	<u>North American Type number</u>	<u>Order code (12nc)</u>	<u>marking/packing</u> <a href="#">Discretes packing info</a>	<u>package</u>	<u>device status</u>	<u>buy online</u>
J174		9340 052 90126	Standard Marking * Ammopack, Radial	<a href="#">SOT54</a> (TO-92; SC-43; SPT; E-1)	Full production	-
J175	J175 T/R	9340 053 00116	Standard Marking * Reel Pack, Radial	<a href="#">SOT54</a> (TO-92; SC-43; SPT; E-1)	Full production	<a href="#">order this</a> -
J176	J176 AMO	9340 053 10126	Standard Marking * Ammopack, Radial	<a href="#">SOT54</a> (TO-92; SC-43; SPT; E-1)	Full production	<a href="#">order this</a> -
J177	J177 AMO	9340 053 20126	Standard Marking * Ammopack, Radial	<a href="#">SOT54</a> (TO-92; SC-43; SPT; E-1)	Full production	<a href="#">order this</a> -

Products in the above table are all in production. Some variants are discontinued; [click here](#) for information on these variants.

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